# Study of Calibration Standards for Extreme Impedances Measurement

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## Outline

- Introduction

   Motivation and main aim
- Measurement theory
- Methodology

   Choice of calibration standards
   CST setting
- Simulated structures

   Basic problems
- Conclusion



#### Introduction

- Motivation
  - Devices with extreme impedances
    - Carbon nanotubes, nanowires, atto-farad varactors, very-weakly coupled resonators
  - Known method for microwave measurement of these structures
    - High sensitivity and accuracy
- Main objective of the project
  - To develop traceable calibration/verification standards for extreme impedance measurement
- Main objective of the presentation
  - To present first simulated result



#### Measurement theory



### Methodology

- Frequency and impedance range
  - Up to 18 GHz



- connector APC-7 (technology, connection repeatability)
- Extremely high impedances
  - $-5 \div 100 \text{ k}\Omega$  (developed measurement method)
- Values of calibration/verification standards
  - 5 kΩ ÷ OPEN
- Required precision in CST
  - At least  $\Delta S = 1 \cdot 10^{-4}$

| Ζ <sub>0</sub> (Ω) | Z <sub>L</sub> (kΩ) | Г <sub>L</sub> (-) |
|--------------------|---------------------|--------------------|
| 50                 | 5                   | 0.980198           |
| 50                 | 10                  | 0.990050           |
| 50                 | 25                  | 0.996008           |
| 50                 | 50                  | 0.998002           |
| 50                 | 100                 | 0.999000           |
| 50                 | OPEN                | 0.9999             |
|                    |                     |                    |



## CST Microwave Studio

- Frequency solver
- Adaptive tetrahedral mesh refinement
  - Criterion  $\Delta S = 1 \cdot 10^{-4}$  reasonable trade-off
- Lossless structures
  - Better understanding
- Resistive strips
  - CrNi (supposed 10 k $\Omega/\Box$ )
- Glass substrate
  - Fused silica ( $\varepsilon_r = 3.8$ )





## Resistor on glass disk



#### **Glass coaxial line**





## Resistor at the end of glass coaxial line



• Strong frequency dependence of reflection coefficient

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Why?



## Dependence on length of glass coaxial line



- Ripples 🤇
  - Multiple reflections at both ends of glass line elimination by the method
- Low frequency degradation



Too short glass line - capacity coupling



- Resistor is only partially effective even on low frequencies
- Bypassed on frequencies above 3GHz



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## E distribution – 5 mm long glass coaxial line



• E distribution around the resistor nearly independent



#### Possible configurations



- Higher order modes limit frequency band
- Still small frequency dependence of resistive strips at low frequencies - unclear



#### Conclusion

- More possible configurations of calibration standards were studied
- Calibration standards for extreme impedance measurements based on the coaxial connector APC-7 are achievable
- Resistive strip(s) placed at the end of glass coaxial line are reasonable solution
- Future tasks
  - Technology dimension optimization
  - Uncertainties determination (mounting repeatability, HFSS simulations)
  - Fabrication of calibration/verification standards
  - Experimental verification



#### Thank you for your attention

